

# WS3A030065K

# Silicon Carbide Schottky Diode

$V_{RRM}$	=	650	V
I <sub>F</sub> ( T <sub>C</sub> ≤135°C)	=	36	A**
$\mathbf{Q}_{C}$	=	72	nC**

### **Features**

- Zero Reverse Recovery Current
- Zero Forward Recovery Voltage
- Positive Temperature Coefficient on V<sub>F</sub>
- Temperature-independent Switching
- 175°C Operating Junction Temperature

### **Benefits**

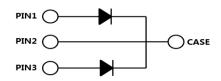
- Replace Bipolar with Unipolar Device
- Reduction of Heat Sink Size
- Parallel Devices Without Thermal Runaway
- Essentially No Switching Losses

## **Applications**

- Switch Mode Power Supplies
- Power Factor Correction
- AC/DC converters

### **Package**



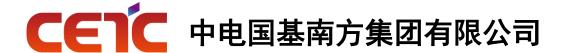


Part Number	Package	Marking
WS3A030065K	TO-247-3	WS3A030065K

## **Maximum Ratings**

Symbol	Parameter	Value	Unit	Test Conditions	Note
$V_{RRM}$	Repetitive Peak Reverse Voltage	650	V	$T_C = 25^{\circ}C$	
V <sub>RSM</sub>	Surge Peak Reverse Voltage	650	V	$T_C = 25^{\circ}C$	
V <sub>R</sub>	DC Blocking Voltage	650	V	T <sub>C</sub> = 25°C	
I <sub>F</sub>	Forward Current (Per leg/Device)	39/78 18/36 15/30	Α	$T_C \le 25^{\circ}C$ $T_C \le 135^{\circ}C$ $T_C \le 151^{\circ}C$	
I <sub>FSM</sub>	Non-Repetitive Forward Surge Current	135*	Α	$T_C = 25^{\circ}C$ , $t_p = 8.3$ ms, Half Sine Wave	
P <sub>tot</sub>	Power Dissipation (Per leg/Device)	161/ 322	W	T <sub>C</sub> = 25°C	Fig.3
Tc	Maximum Case Temperature	151	°C		
T <sub>J</sub> , T <sub>STG</sub>	Operating Junction and Storage Temperature	-55 to 175	°C		
	TO-247 Mounting Torque	1	Nm	M3 Screw	

<sup>\*</sup>Per Leg, \*\*Per Device



## **Electrical Characteristics (Per Leg)**

Symbol	Parameter	Тур.	Max.	Unit	Test Conditions	Note
V	Famuuard Valtage	1.4	1.65	V	I <sub>F</sub> = 15A, T <sub>J</sub> = 25°C	Fig. 4
$V_{F}$	Forward Voltage	1.75	2.3 V	I <sub>F</sub> = 15A, T <sub>J</sub> = 175°C	Fig.1	
	B	1	20		$V_R = 650V, T_J = 25^{\circ}C$	F: 0
I <sub>R</sub>	Reverse Current	5 100	μA	V <sub>R</sub> = 650V, T <sub>J</sub> = 175°C	Fig.2	
		865			$V_R = 0V, T_J = 25^{\circ}C, f = 1MHz$	
С	Total Capacitance	88	/	pF	$V_R = 200V, T_J = 25^{\circ}C, f = 1MHz$	Fig.5
		72			$V_R = 400V, T_J = 25^{\circ}C, f = 1MHz$	
	T	00			V <sub>R</sub> = 650V, I <sub>F</sub> = 15A	1
$Q_{C}$	Total Capacitive Charge	Total Capacitive Charge 36 /	/	nC	di/dt = 200A/μs, T <sub>J</sub> = 25°C	Fig.4

### **Thermal Characteristics**

Symbol	Parameter	Тур.	Unit	Note
R <sub>θJC</sub>	R <sub>BJC</sub> Thermal Resistance from Junction to Case		°C/W	Fig.6
R <sub>0JA</sub> Thermal Resistance from Junction to Ambient		80	°C/W	
T <sub>sold</sub> Soldering Temperature		260	°C	

<sup>\*</sup>Per Leg, \*\*Per Device

## **Typical Performance (Per Leg)**

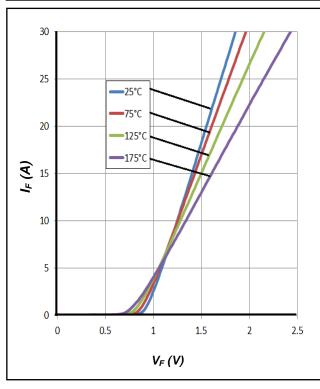


Figure 1. Forward Characteristics

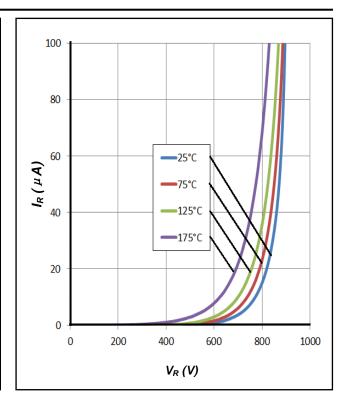
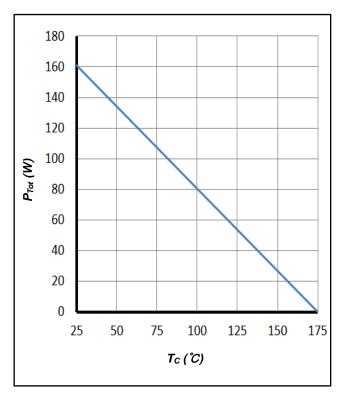


Figure 2. Reverse Characteristics

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# **Typical Performance (Per Leg)**



40 35 30 25 20 15 10 5 0 100 200 300 400 500 600 700 V<sub>R</sub> (V)

Figure 3. Power Derating

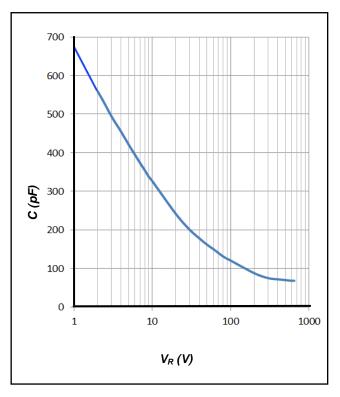


Figure 5. Total Capacitance vs. Reverse Voltage

Figure 4. Total Capacitive Charge vs. Reverse Voltage

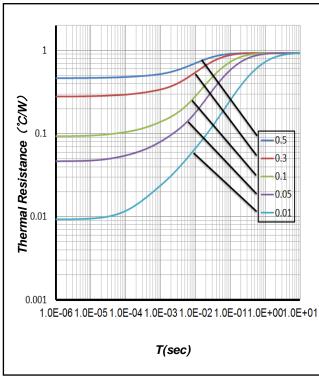
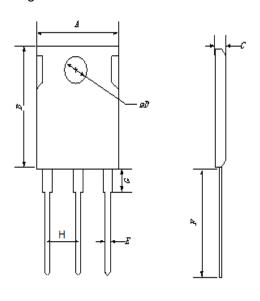


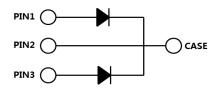
Figure 6. Transient Thermal Impedance

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### **Package Dimensions**

Package TO-247-3

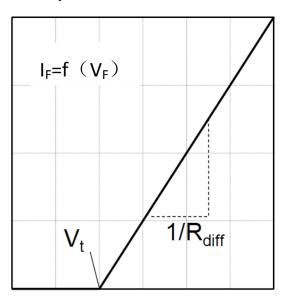




Symbol	Min. (mm)	Typ. (mm)	Max. (mm)
Α	14.18	15.75	17.33
В	18.45	20.5	22.55
С	4.50	5.00	5.50
D	3.15	3.50	3.85
E	1.08	1.20	1.32
F	18.27	20.30	22.33
G	4.21	4.68	5.15
Н	4.91	5.46	6.01

### Simplified Diode Model (Per Leg)

### **Equivalent IV Curve for Model**



### **Mathematical Equation**

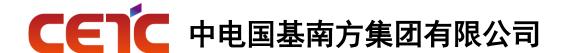
$$V_F = V_t + I_F \times R_{diff}$$

$$\begin{split} &V_t = -0.0011 \textbf{x} T_j + 0.982 \ [V] \\ &R_{diff} = 3.38 \textbf{x} 10^{-7} \textbf{x} T_j^2 + 2.78 \textbf{x} 10^{-5} \textbf{x} T_j + 0.0169 \ [\Omega] \end{split}$$

#### Note:

Tj = Diode Junction Temperature In Degrees Celsius, valid from 25°C to 175°C  $I_{\text{F}}$ = Forward Current

Less than 60A



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